SCS220AM

SiC Schottky Barrier Diode

Datasheet

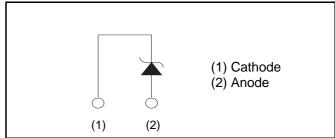
V_R	650V
I _F	20A
Q_C	31nC

Outline TO-220FM

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

●Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

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	Packaging	Tube		
	Reel size (mm)	-		
Typo	Tape width (mm)	-		
Туре	Basic ordering unit (pcs)	50		
	Packing code	С		
	Marking	SCS220AM		

•Absolute maximum ratings $(T_i = 25^{\circ}C)$

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	650	V
Reverse voltage (DC)		V_R	650	V
Continuous forward	current (T _c = 21°C)	I _F	20	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		68	А
repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I _{FSM}	53	А
	PW=10μs square, T _j =25°C		260	А
Repetitive peak forward current		I _{FRM}	41 *1	А
PW=10ms, T _j =25°C		ر ری ر	23	A ² s
i ² t value	PW=10ms, T _j =150°C	$\int i^2 dt$	14	A ² s
Total power disspation		P_{D}	40 *2	W
Junction temperature		T_j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_j=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =4.0mA	650	-	-	V
	V _F	I _F =20A,T _j =25°C	-	1.35	1.55	V
Forward voltage		I _F =20A,T _j =150°C	-	1.55	-	V
		I _F =20A,T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	4	400	μΑ
		V _R =650V,T _j =150°C	-	60	1	μΑ
		V _R =650V,T _j =175°C	-	140	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	730	-	pF
		V _R =600V,f=1MHz	-	74	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	31	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	19	-	ns

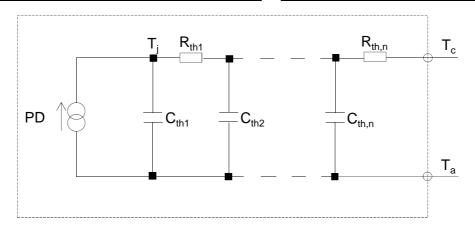
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	3.2	3.7	°C/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	5.45E-01	
R _{th2}	1.17E+00	K/W
R _{th3}	1.50E+00	

Symbol	Value	Unit
C_{th1}	2.76E-03	
C_{th2}	9.35E-03	Ws/K
C_{th3}	8.16E-01	



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

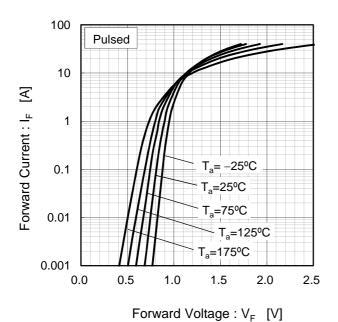
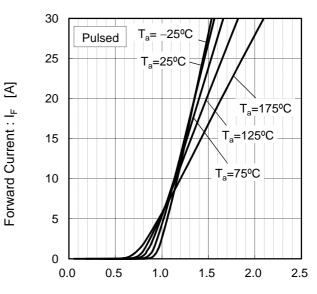


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

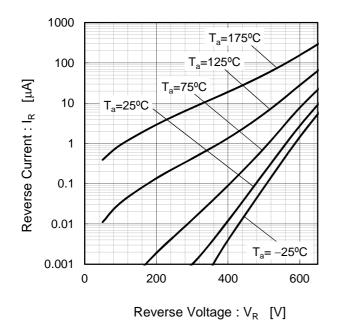
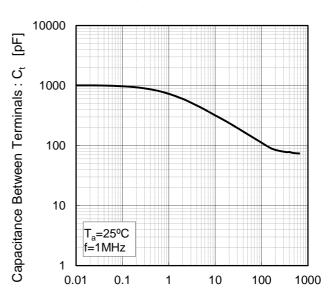


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

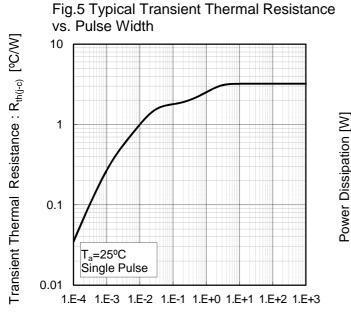
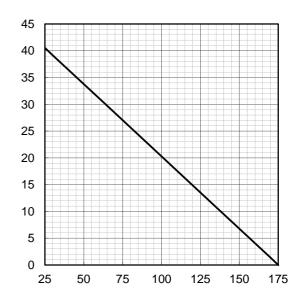


Fig.6 Power Dissipation



Pulse Width: PW [s]

Case Temperature : T_c [°C]

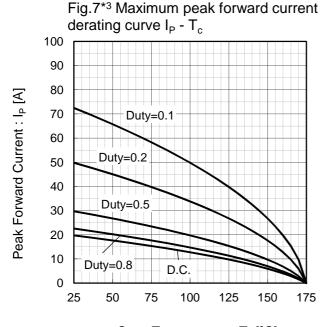
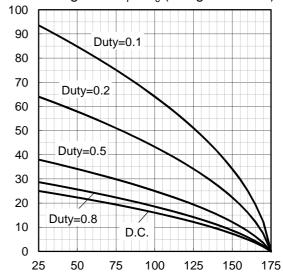


Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



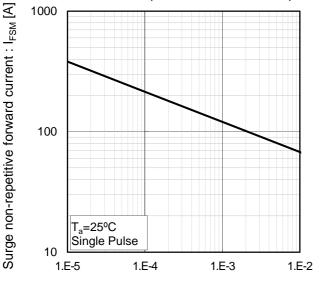
Case Temperature : T_c [°C] *3 Based on max Vf, max $R_{th(j-c)}$ Valid for switching of above 10kHz, excluding D.C. curve.

Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current : I_P [A]

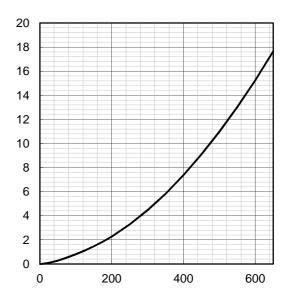
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig. 10 Typical capacitance store energy

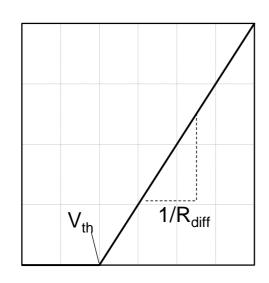


Capacitance stored energy : $\mathsf{E}_\mathsf{C}[\mathsf{\mu} \mathsf{J}]$

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.35E-01	V
a ₁	-1.12E-03	V/°C
b ₀	1.99E-02	Ω
b ₁	5.10E-05	Ω/°C
b ₂	5.40E-07	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < °C; I_F < 40 A

Forward Current: I_F

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